

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: T. KOBAYASHI

Application No.: Rule 1.53(b) Continuation of U.S. Patent Application
Serial No. 09/811,444, filed March 20, 2001

Filed: On even date herewith

For: NONVOLATILE SEMICONDUCTOR MEMORY DEVICE
WITH IMPROVED GATE OXIDE FILM ARRANGEMENT
(As Amended)

Art Group of Parent: 2826

Examiner of Parent: K. Quinto

PRELIMINARY AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

October 15, 2003

Sir:

Prior to examination, please amend the above-identified application as listed below and as set forth on the following pages:

Amendments to the Specification and Title

Amendments to the claims and

Remarks are included after the amendments.